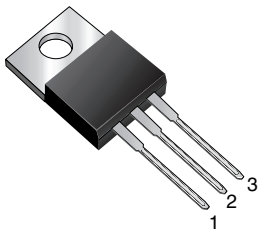
Dual Trench MOS Barrier Schottky Rectifier

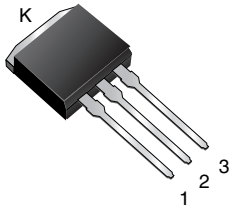
Ultra Low V_F = 0.49 V at I_F = 3 A

TMBS®

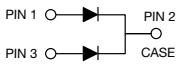
TO-220AB



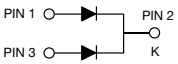
TO-262AA



VT1080C



VIT1080C



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 5 A
V_{RRM}	80 V
I_{FSM}	80 A
V_F at I_F = 5 A	0.57 V
T_J max.	150 °C
Package	TO-220AB, TO-262AA
Diode variations	Common cathode

MECHANICAL DATA

Case: TO-220AB and TO-262AA
Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade
Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

PARAMETER		SYMBOL	VT1080C	VIT1080C	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	80		V
Maximum average forward rectified current (fig. 1)	per device	$I_{F(AV)}$	10		A
	per diode		5		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I_{FSM}	80		A
Voltage rate of change (rated V_R)		dV/dt	10 000		V/µs
Operating junction and storage temperature range		T_J, T_{STG}	-55 to +150		°C

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	**TEST CONDITIONS**		**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Instantaneous forward voltage per diode	I_F = 3 A	T_A = 25 °C	V_F (1)	0.54	-	V
	I_F = 5 A			0.63	0.72	
	I_F = 3 A	T_A = 125 °C		0.49	-	
	I_F = 5 A			0.57	0.66	
Reverse current per diode	V_R = 80 V	T_A = 25 °C	I_R (2)	12	400	µA
		T_A = 125 °C		6	15	mA

Notes
(1) Pulse test: 300 µs pulse width, 1 % duty cycle
(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)					
PARAMETER		**SYMBOL**	**VT1080C**	**VIT1080C**	**UNIT**
Typical thermal resistance	per diode	$R_{\theta JC}$	3.5		°C/W
	per device		2.5		

ORDERING INFORMATION (Example)					
PACKAGE	**PREFERRED P/N**	**UNIT WEIGHT (g)**	**PACKAGE CODE**	**BASE QUANTITY**	**DELIVERY MODE**
TO-220AB	VT1080C-M3/4W	1.88	4W	50/tube	Tube
TO-262AA	VIT1080C-M3/4W	1.43	4W	50/tube	Tube
TO-220AB	VT1080CHM3/4W (1)	1.88	4W	50/tube	Tube
TO-262AA	VIT1080CHM3/4W (1)	1.43	4W	50/tube	Tube

Note
(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

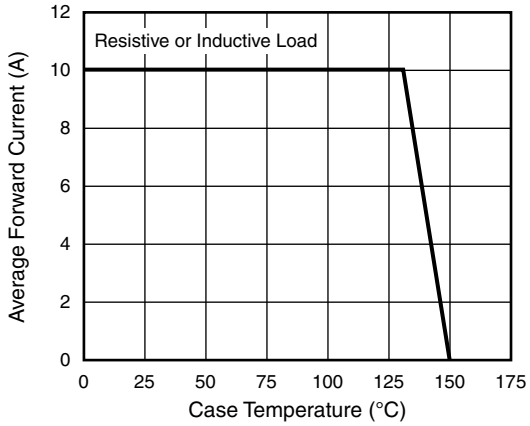


Fig. 1 - Maximum Forward Current Derating Curve

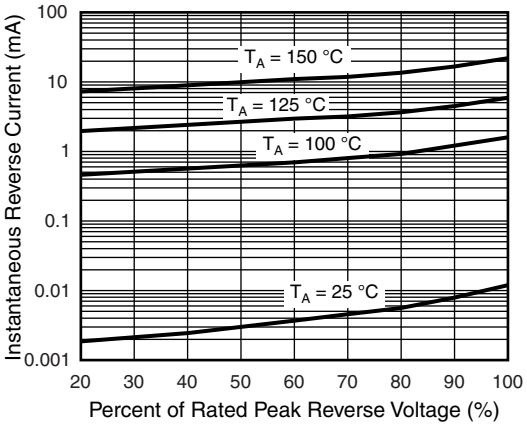


Fig. 4 - Typical Reverse Characteristics

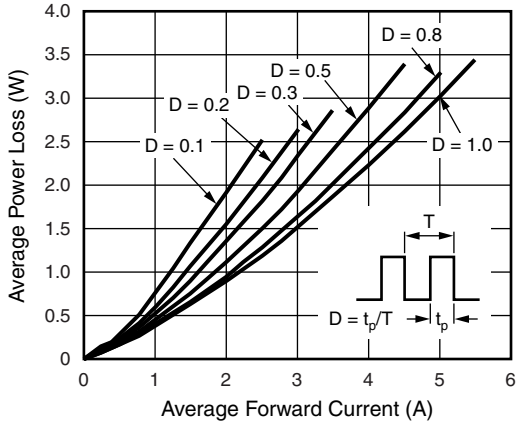


Fig. 2 - Forward Power Dissipation Characteristics

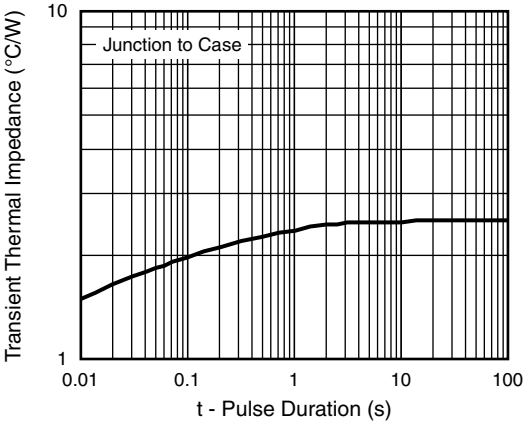


Fig. 5 - Typical Transient Thermal Impedance

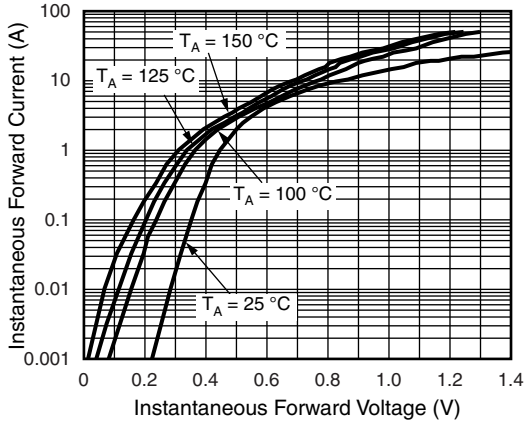


Fig. 3 - Typical Instantaneous Forward Characteristics

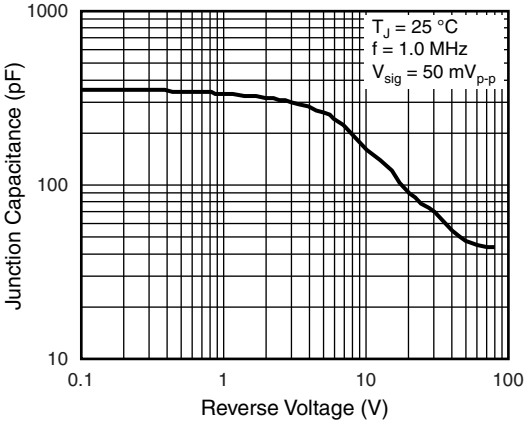
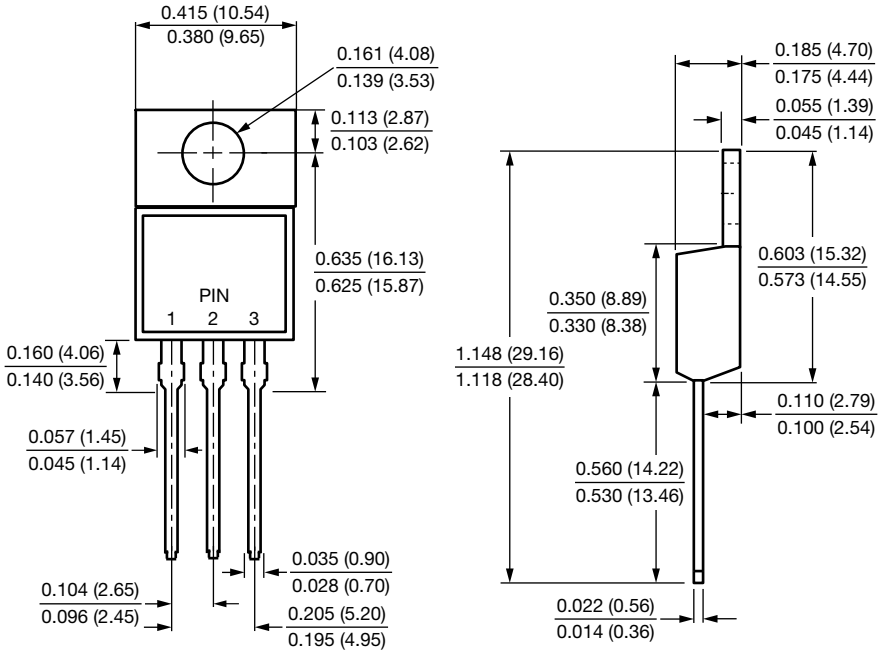


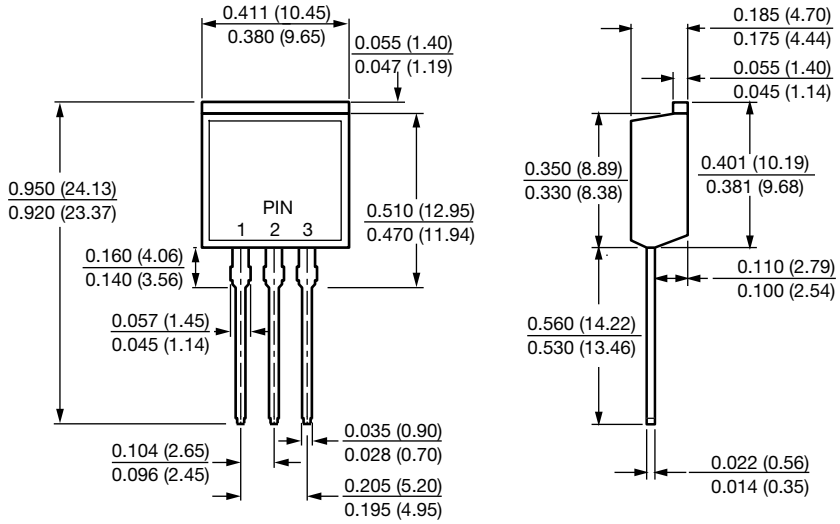
Fig. 6 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



TO-262AA



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